

SYLLABUS

2nd Year - III Semester: B.Tech. (Electronics Instrumentation & Control)

3EI1-02/4EI1-02: Technical Communication

2 Credit 2L:0T:0P

Max. Marks: 100 (IA:20, ETE:80) End Term Exam: 2 Hours

SN	Contents	Hours
1	Introduction to Technical Communication- Definition of technical communication, Aspects of technical communication, forms of technical communication, importance of technical communication, technical communication skills (Listening, speaking, writing, reading writing), linguistic ability, style in technical communication.	4
2	Comprehension of Technical Materials/Texts and Information Design & development- Reading of technical texts, Readingand comprehending instructions and technical manuals, Interpreting and summarizing technical texts, Note-making. Introduction of different kinds of technical documents, Information collection, factors affecting information and document design, Strategies for organization, Information design and writing for print and online media.	6
3	Technical Writing, Grammar and Editing - Technical writing process, forms of technical discourse, Writing, drafts and revising, Basics of grammar, common error in writing and speaking, Study of advanced grammar, Editing strategies to achieve appropriate technical style, Introduction to advanced technical communication. Planning, drafting and writing Official Notes, Letters, E-mail, Resume, Job Application, Minutes of Meetings.	8
4	Advanced Technical Writing - Technical Reports, types of technical reports, Characteristics and formats and structure of technical reports. Technical Project Proposals, types of technical proposals, Characteristics and formats and structure of technical proposals. Technical Articles, types of technical articles, Writing strategies, structure and formats of technical articles.	8
	Total	26



SYLLABUS

2nd Year - III Semester: B.Tech. (Electronics Instrumentation & Control)

3EI1-03/4EI1-03: Managerial Economics And Financial Accounting Credit Max. Marks: 100 (IA:20, ETE:80)

2 Credit 2L:0T:0P

End Term Exam: 2 Hours

SN	Contents	Hours
1	Basic economic concepts- Meaning, nature and scope of economics, deductive vs inductive methods, static and dynamics, Economic problems: scarcity and choice, circular flow of economic activity, national income-concepts and measurement.	4
2	Demand and Supply analysis- Demand-types of demand, determinants of demand, demand function, elasticity of demand, demand forecasting –purpose, determinants and methods, Supply-determinants of supply, supply function, elasticity of supply.	5
3	Production and Cost analysis- Theory of production- production function, law of variable proportions, laws of returns to scale, production optimization, least cost combination of inputs, isoquants. Cost concepts-explicit and implicit cost, fixed and variable cost, opportunity cost, sunk costs, cost function, cost curves, cost and output decisions, cost estimation.	5
4	Market structure and pricing theory- Perfect competition, Monopoly, Monopolistic competition, Oligopoly.	4
5	Financial statement analysis- Balance sheet and related concepts, profit and loss statement and related concepts, financial ratio analysis, cash-flow analysis, funds-flow analysis, comparative financial statement, analysis and interpretation of financial statements, capital budgeting techniques.	8
	Total	26



SYLLABUS

2nd Year - III Semester: B.Tech. (Electronics Instrumentation & Control)

3EI4-04: Digital System Design

3 CreditsMax. Marks: 150 (IA:30, ETE:120)3L:0T:0PEnd Term Exam: 3 Hours

SN	Contents	Hours
1	Logic Simplification and Combinational Logic Design: Review of Boolean Algebra and De Morgan's Theorem, SOP & POS forms, Canonical forms, Karnaugh maps up to 6 variables, Binary codes, Code Conversion.	7
2	MSI devices like Comparators, Multiplexers, Encoder, Decoder, Driver & Multiplexed Display, Half and Full Adders, Subtractors, Serial and Parallel Adders, BCD Adder, Barrel shifter and ALU	8
3	Sequential Logic Design: Building blocks like S-R, JK and Master- Slave JK FF, Edge triggered FF, Ripple and Synchronous counters, Shift registers, Finite state machines, Design of Synchronous FSM, Algorithmic State Machines charts. Designing synchronous circuits like Pulse train generator, Pseudo Random Binary Sequence generator, Clock generation.	9
4	Logic Families and Semiconductor Memories: TTL NAND gate, Specifications, Noise margin, Propagation delay, fan-in, fan-out, Tristate TTL, ECL, CMOS families and their interfacing, memory elements, Concept of Programmable logic devices like FPGA. Logic implementation using programmable devices.	8
5	VLSI Design flow: Design entry: Schematic, FSM & HDL, different modeling styles in VHDL, Data types and objects, Dataflow, Behavioral and Structural Modeling, Synthesis and Simulation VHDL constructs and codes for combinational and sequential circuits.	8
	Total	40



SYLLABUS

2nd Year - III Semester: B.Tech. (Electronics Instrumentation & Control)

Course Outcome:

Course Code	Course Name	Course Outco me	Details
3EI4-04		CO 1	Develop the understanding of number system and its application in digital electronics.
	Digital System Design	CO 2	Development and analysis of K-map to solve the Boolean function to the simplest form for the implementation of compact digital circuits.
		CO 3	Design various combinational and sequential circuits using various metrics: switching speed, throughput/latency, gate count and area, energy dissipation and power.
		CO 4	Understanding Interfacing between digital circuits and analog component using Analog to Digital Converter (ADC), Digital to Analog Converter (DAC) etc.
		CO 5	Design and implement semiconductor memories, programmable logic devices (PLDs) and field programmable gate arrays (FPGA) in digital electronics.

CO-PO Mapping:

Subject	Course Outcom es	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10	PO 11	PO 12
я	CO 1	3	2	2	1		1						
)4 /stei n	CO 2	3	2	3	2								
)14-0 al Sy esig	CO 3	2	2	3	1	1							
3E jigita	CO 4	3	2	1	1	1							
A	CO 5	2	1	3	1	1							
	3: 5	Strong	gly	2	2: Mo	dera	te	1	Raj	: We Office o asthan	ak f Dean Technie	Academ cal Univ	ic Affai versity,



SYLLABUS

2nd Year - III Semester: B.Tech. (Electronics Instrumentation & Control)

Lecture Plan:

Lecture	Content to be taught
No.	
Lecture 1	Zero Lecture
Lecture 2	Review of Boolean Algebra
Lecture 3	DeMorgan's Theorem, SOP & POS forms,
Lecture 4	Problem of SOP and POS forms of boolean functions.
Lecture 5	Simplification of karnaugh map up to 6 variables
Lecture 6	Simplification of karnaugh map up to 6 variables
Lecture 7	Simplification of karnaugh map up to 6 variables
Lecture 8	Binary codes and code conversion
Lecture 9	Binary codes and code conversion
Lecture 10	Encoder, Decoder
Lecture 11	Half and Full Adders, Subtractors, Serial and Parallel Adders
Lecture 12	BCD Adder, Barrel shifter
Lecture 13	S-R FF, edge triggered and level triggered
Lecture 14	D and J-K FF
Lecture 15	Master-Slave JK FF and T FF
Lecture 16	Ripple and Synchronous counters
Lecture 17	Other type of counters
Lecture 18	Shift registers, Finite state machines, Asynchronous FSM
Lecture 19	Design of synchronous FSM
Lecture 20	Design of synchronous FSM
Lecture 21	Design of synchronous FSM
Lecture 22	Designing synchronous circuits (pulse train generator, pseudo random binary sequence generator, clock generation)
·	



SYLLABUS

2nd Year - III Semester: B.Tech. (Electronics Instrumentation & Control)

Lecture 23	TTL NAND gate, specifications, noise margin, propagation delay, fan-in, fan-out							
Lecture 24	TL NAND gate							
Lecture 25	Tristate TTL, ECL							
Lecture 26	CMOS families and their interfacing							
Lecture 27	CMOS families and their interfacing							
Lecture 28	Read-Only Memory, Random Access Memory							
Lecture 29	Programmable Logic Arrays (PLA)							
Lecture 30	Programmable Array Logic (PAL),							
Lecture 31	Field Programmable Gate Array (FPGA)							
Lecture 32	Combinational PLD-Based State Machines,							
Lecture 33	State Machines on a Chip							
Lecture 34	Schematic, FSM & HDL							
Lecture 35	Different modeling styles in VHDL							
Lecture 36	Data types and objects, Data flow							
Lecture 37	Behavioral and Structural Modeling							
Lecture 38	Behavioral and Structural Modeling							
Lecture 39	Simulation VHDL constructs and codes for combinational and sequential circuits							
Lecture 40	Simulation VHDL constructs and codes for combinational and sequential circuits							

Content delivery method:

- **1.** Chalk and Duster
- **2.** PPT
- 3. Hand-outs



SYLLABUS

2nd Year - III Semester: B.Tech. (Electronics Instrumentation & Control)

Sample Assignments:

Assignment 1	Q1. Using K-maps, find the minimal Boolean expression of the following SOP and POS representations. a f (w x y z)= Σ (7 13 14 15)							
	b. $f(w,x,y,z) = \Sigma (1,3,4,6,9,11,14,15)$							
	c. $f(w,x,y,z) = \Pi(1,4,5,6,11,12,13,14,15)$							
	d. $f(w,x,y,z) = \Sigma (1,3,4,5,7,8,9,11,15)$							
	e. $f(w,x,y,z) = \Pi (0,4,5,7,8,9,13,15)$							
	Q2. Find the function $h(a,b,c,d)$ such that $f = f^d$. $f(a,b,c,d) = a \cdot b \cdot c + (a \cdot c + b) \cdot d + h(a,b,c,d)$							
	Q3. Using K-maps of the functions f1 and f2, find the following: (provide							
	the canonical form expression and simplify)							
	a. T1 = f1 \cdot f2							
	b. $T2 = f1 + f2$							
	c. T3 = f1 \oplus f2							
	where f1(w,x,y,z) = Σ (0,2,4,9,12,15), f2(w,x,y,z) = Σ (1,2,4,5,12,13)							
Assignment 2	Q1 . Draw the state diagram of a serial adder.							
	Q2. In the following circuit, given binary values were applied to the							
	Inputs X and Y inputs of the NAND latch shown in the figure. X =							
	0, Y = 1; X = 0, Y = 0; X = 1, Y = 1. Find out the corresponding stable output P, Q.							



SYLLABUS

2nd Year - III Semester: B.Tech. (Electronics Instrumentation & Control)





SYLLABUS

2nd Year - III Semester: B.Tech. (Electronics Instrumentation & Control)

3EI4-05: Signals & Systems

3 Credits 3L:0T:0P

SN	Contents	Hours
1	Energy and power signals, continuous and discrete time signals, continuous and discrete amplitude signals. System properties: linearity: additivity and homogeneity, shift-invariance, causality, stability, realizability.	6
2	Linear shift-invariant (LSI) systems, impulse response and step response, convolution, input output behavior with aperiodic convergent inputs. Characterization of causality and stability of linear shift-invariant systems. System representation through differential equations and difference equations	7
3	Periodic and semi-periodic inputs to an LSI system, the notion of a frequency response and its relation to the impulse response, Fourier series representation, the Fourier Transform, convolution/multiplication and their effect in the frequency domain, magnitude and phase response, Fourier domain duality. The Discrete-Time Fourier Transform (DTFT) and the Discrete Fourier Transform (DFT). Parseval's Theorem. The idea of signal space and orthogonal bases	8
4	The Laplace Transform, notion of eigen functions of LSI systems, a basis of eigen functions, region of convergence, poles and zeros of system, Laplace domain analysis, solution to differential equations and system behavior.	6
5	The z-Transform for discrete time signals and systems- eigen functions, region of convergence, z-domain analysis.	5
б	State-space analysis and multi-input, multi-output representation. The state-transition matrix and its role. The Sampling Theorem and its implications- Spectra of sampled signals. Reconstruction: ideal interpolator, zero-order hold, first-order hold, and so on. Aliasing and its effects. Relation between continuous and discrete time systems.	8
	Total	40



SYLLABUS

2nd Year - III Semester: B.Tech. (Electronics Instrumentation & Control)

Course Outcome:

Course	Course	Course	Dotaila					
Code	Name	Outcome	Details					
		CO 1	Analyze different types of signals and system properties					
E14-05	ignals & lystems	CO 2	Represent continuous and discrete systems in time and frequency domain using different transforms					
		CO 3	Investigate whether the system is stable.					
3	S. S.	CO 4	Sampling and reconstruction of a signal.					
		CO 5	Acquire an understanding of MIMO systems					

CO-PO Mapping:

Subject	Course Outcom es	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10	PO 11	PO 12
sm	CO 1	3	3	1	2	2			1				2
)5 yste	CO 2	3	1		2	3			1				2
8° S	CO 3	3	2	2	3								2
3E nals	CO 4	3	2	3	3	1							
Sig	CO 5	3	2	2	3	1			2				1
<u> </u>	3: \$	Stron	gly	2	2: Mo	dera	te	•	1	: We	ak	•	•



SYLLABUS

2nd Year - III Semester: B.Tech. (Electronics Instrumentation & Control) Lecture Plan:

Lecture No.	Content to be taught
Lecture 1	Zero Lecture
Lecture 2	Energy signals power signals
Lecture 3	Continuous and discrete time signals
Lecture 4	Continuous amplitude signals
Lecture 5	and discrete amplitude signals
Lecture 6	System properties: linearity: additivity and homogeneity
Lecture 7	shift-invariance, causality
Lecture 8	stability, realizability.
Lecture 9	Linear shift-invariant (LSI) systems
Lecture 10	impulse response
Lecture 11	Step response
Lecture 12	Convolution.
Lecture 13	Input output behavior with aperiodic convergent inputs
Lecture 14	Characterization of causality and stability of linear shift-invariant systems.
Lecture 15	System representation through differential equations and difference equations.
Lecture 16	Characterization of causality and stability of linear shift-invariant systems.
Lecture 17	System representation through differential equations and difference equations.
Lecture 18	Periodic and semi-periodic inputs to an LSI system
Lecture 19	The notion of a frequency response.
Lecture 20	Its relation to the impulse response
Lecture 21	Fourier series representation
Lecture 22	Fourier Transform
Lecture 23	Convolution/multiplication and their effect in the frequency
	Rajasthan Technical University, Kota



SYLLABUS

2nd Year	- III Semester: B.Tech. (Electronics Instrumentation & Control)
	domain
Lecture 24	Magnitude and phase response
Lecture 25	Fourier domain duality.
Lecture 26	The Discrete-Time Fourier Transform (DTFT) and Discrete Fourier Transform (DFT).
Lecture 27	Parseval's Theorem. The idea of signal space and orthogonal bases
Lecture 28	The Laplace Transform
Lecture 29	Notion of eigen functions of LSI systems
Lecture 30	A basis of eigen functions, region of convergence
Lecture 31	Poles and zeros of system, Laplace domain analysis,
Lecture 32	Solution to differential equations and system behavior.
Lecture 33	The z-Transform for discrete time signals and systems- eigen functions,
Lecture 34	Region of convergence, z-domain analysis.
Lecture 35	State-space analysis and multi-input, multi-output representation.
Lecture 36	The state-transition matrix and its role.
Lecture 37	The Sampling Theorem and its implications- Spectra of sampled signals.
Lecture 38	Reconstruction: ideal interpolator, zero-order hold, first-order hold, and so on
Lecture 39	Aliasing and its effects.
Lecture 40	Relation between continuous and discrete time systems.

Content delivery method:

- **1.** Chalk and Duster
- **2.** PPT
- **3.** Animation
- **4.** Hand-outs



SYLLABUS

2nd Year - III Semester: B.Tech. (Electronics Instrumentation & Control) Assignments:



SYLLABUS

2nd Year - III Semester: B.Tech. (Electronics Instrumentation & Control)

Evaluate the following sums:

(a)
$$\sum_{n=0}^{5} 2\left(\frac{3}{a}\right)^{n}$$

(b)
$$\sum_{n=2}^{6} b^{n}$$

(c)
$$\sum_{n=0}^{\infty} \left(\frac{2}{3}\right)^{2n}$$

Hint: Convert each sum to the form

$$C\sum_{n=0}^{N-1} \alpha^n = S_N$$
 or $C\sum_{n=0}^{\infty} \alpha^n = S_{\infty}$

and use the formulas

$$S_{\scriptscriptstyle N} = C\left(rac{1-lpha^{\scriptscriptstyle N}}{1-lpha}
ight), \qquad S_{\scriptscriptstyle \infty} = rac{C}{1-lpha} \qquad {
m for} \ |lpha| < 1$$

Q2.

The first-order difference equation y[n] - ay[n - 1] = x[n], 0 < a < 1, describes a particular discrete-time system initially at rest.

(a) Verify that the impulse response h[n] for this system is h[n] = aⁿu[n].

- (b) Is the system
 - (i) memoryless?
 - (ii) causal?
 - (iii) stable?

Clearly state your reasoning.

(c) Is this system stable if |a| > 1?

Q3.



SYLLABUS





SYLLABUS

2nd Year - III Semester: B.Tech. (Electronics Instrumentation & Control)

3EI4-06: Network Theory

4 CreditsMax. Marks: 200 (IA:40, ETE:160)3L:1T:0PEnd Term Exam: 3 Hours

SN	Contents	Hours
1	Node and Mesh Analysis, matrix approach of network containing voltage and current sources, andreactances, source transformation and duality.	7
2	Network theorems: Superposition, reciprocity, Thevenin's, Norton's, Maximum power Transfer, compensation and Tallegen's theorem as applied to AC. circuits.	7
3	Trigonometric and exponential Fourier series: Discrete spectra and symmetry of waveform, steady state response of a network to non- sinusoidal periodic inputs, power factor, effective values, Fourier transform and continuous spectra, three phase unbalanced circuit and power calculation.	8
4	Laplace transforms and properties: Partial fractions, singularity functions, waveform synthesis, analysis of RC, RL, and RLC networks with and without initial conditions with Laplace transforms evaluation of initial conditions.	8
5	Transient behavior, concept of complex frequency, Driving points and transfer functions poles and zeros of immittance function, their properties, sinusoidal response from pole-zero locations, convolution theorem and Two four port network and interconnections, Behaviors of series and parallel resonant circuits, Introduction to band pass, low pass, high pass and band reject filters.	10
	Total	40





SYLLABUS

2nd Year - III Semester: B.Tech. (Electronics Instrumentation & Control) Course Outcome:

Course Code	Course Name	Course Outcome	Details
		CO 1	Apply the basic circuital law and simplify the network using network theorems
96	heory	CO 2	Appreciate the frequency domain techniques in different applications.
EI4-0	ork T	CO 3	Apply Laplace Transform for steady state and transient analysis
Ö	Netwo	CO 4	Evaluate transient response and two-port network parameters
	ſ	CO 5	Analyze the series resonant and parallel resonant circuit and design filters

CO-PO Mapping:

Subject	Course Outcome s	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10	PO 11	PO 12
ry	CO 1	3	2		3	2							
)6 'heo	CO 2	3	3	1	2	2							1
014-0 rk T	CO 3	3	2	2		2							1
3I etwo	CO 4	2	3	2	2	1							
Ň	CO 5	2	3	3	2	1							
	3: \$	Strong	gly	2	2: Mo	derat	te		1	: We	ak		



SYLLABUS

2nd Year - III Semester: B.Tech. (Electronics Instrumentation & Control)

Lecture Plan:

Lecture No.	Content to be taught								
Lecture 1	Overview of Network Theory and its significance								
Lecture 2	Node and Mesh Analysis								
Lecture 3	matrix approach of network containing voltage and current								
	sources and reactances								
Lecture 4	source transformation and duality								
Lecture 5	Network theorems: Superposition and reciprocity								
Lecture 6	Thevenin's and Norton's theorem								
Lecture 7	Maximum power Transfer theorem								
Lecture 8	compensation and Tallegen's theorem as applied to AC. Circuits								
Lecture 9	Trigonometric and exponential Fourier series								
Lecture 10	Fourier series: Discrete spectra and symmetry of waveform								
Lecture 11	Steady state response of a network to non-sinusoidal periodic								
	inputs								
Lecture 12	power factor and effective values								
Lecture 13	Fourier transform and continuous spectra								
Lecture 14	three phase unbalanced circuit and power calculation								
Lecture 15	three phase unbalanced circuit and power calculation								
Lecture 16	Laplace transforms								
Lecture 17	Laplace transforms								
Lecture 18	Laplace transforms properties: Partial fractions								
Lecture 19	singularity functions and waveform synthesis								
Lecture 20	analysis of RC networks								
Lecture 21	analysis of RL networks								
Lecture 22	analysis of RLC networks								
Lecture 23	Analysis of networks with and without initial conditions								
Lecture 24	Analysis of networks with and without initial conditions								
Lecture 25	Analysis of networks with and without initial conditions with								
	lapalace transforms evaluation								
Lecture 26	Analysis of networks with and without initial conditions with								
	lapalace transforms evaluation of initial condition								
Lecture 27	Transient behavior								
Lecture 28	concept of complex frequency								
Lecture 29	Driving points and transfer functions poles and zeros of								
	immittance function								
Lecture 30	Driving points and transfer functions poles and zeros of								
	immittance function: their properties								
Lecture 31	sinusoidal response from pole-zero locationstice of Dean Academic Affairs								
	Rajasthan Technical University, Kota								



SYLLABUS

2nd Year - III Semester: B.Tech. (Electronics Instrumentation & Control)

Lecture 32	sinusoidal response from pole-zero locations
Lecture 33	convolution theorem
Lecture 34	sinusoidal response from pole-zero locations
Lecture 35	Two four port network and interconnections
Lecture 36	Two four port network and interconnections
Lecture 37	Behaviors of series and parallel resonant circuits
Lecture 38	Introduction to band pass and low pass
Lecture 39	Introduction to high pass and reject filters
Lecture 40	Spill over class

Content delivery method:

- 1. Chalk and Duster
- **2.** PPT
- 3. Hand-outs

SYLLABUS

2nd Year - III Semester: B.Tech. (Electronics Instrumentation & Control) Sample assignments:

Assignment 1	Q1.	Elaborate the significance of source transformation with relevant example
	Q2.	State and prove time differentiation theorem in Laplace Transform
	Q3.	Find the Thevenin equivalent of the network shown in figure. What power would be delivered to a load of 100 ohms at <i>a</i> and <i>b</i> ?
		$20 \text{ V} \stackrel{40 \Omega}{=} \underbrace{200 \Omega}_{i_1} \underbrace{100 \Omega}_{1.5i_1} \underbrace{1.5i_1}_{i_1} \underbrace{1.5i_1}_{0 b}$
Assignment 2	Q4.	Calculate The venin equivalent circuit with respect to terminals a and b
		$-j300 \Omega$ $200 \Omega j100 \Omega$ $100 / 0^{\circ} V + 100 / 90^{\circ} V + b$
	Q5.	Derive transient current and voltage responses of sinusoidal driven RL and RC circuits.
	Q6.	Specify the restrictions on pole and zero locations for transfer functions and driving-point functions.



SYLLABUS

2nd Year - III Semester: B.Tech. (Electronics Instrumentation & Control)

3EI4-07: Electronic Devices

4 Credits 3L:1T:0P

Max. Marks: 200 (IA:40, ETE:160) End Term Exam: 3 Hours

SN	Contents	Hours
1	Introduction to Semiconductor Physics: Introduction, Energy band gap structures of semiconductors, Classifications of semiconductors, Degenerate and non-degenerate semiconductors, Direct and indirect band gap semiconductors, Electronic properties of Silicon, Germanium, Compound Semiconductor, Gallium Arsenide, Gallium phosphide & Silicon carbide, Variation of semiconductor conductivity, resistance and bandgap with temperature and doping. Thermistors, Sensitors.	6
2	Review of Quantum Mechanics, Electrons in periodic Lattices, E-k diagrams. Energy bands in intrinsic and extrinsic silicon; Carrier transport: diffusion current, drift current, mobility and resistivity; sheet resistance, design of resistors.	6
3	Generation and recombination of carriers; Poisson and continuity equation P-N junction characteristics, I-V characteristics, and small signal switching models; Avalanche breakdown, Zener diode, Schottky diode.	8
4	Bipolar Junction Transistor, I-V characteristics, Ebers-Moll Model, MOS capacitor, C-V characteristics, MOSFET, I-V characteristics, and small signal models of MOS transistor, LED, photodiode and solar cell.	11
5	Integrated circuit fabrication process: oxidation, diffusion, ion implantation, Photolithography, etching, chemical vapor deposition, sputtering, twin-tub CMOS process.	9
	Total	40



SYLLABUS

2nd Year - III Semester: B.Tech. (Electronics Instrumentation & Control)

Course Outcome:

Course Code	Course Name	Course Outco me	Details
		CO 1	Understanding the semiconductor physics of the intrinsic, P and N materials.
	vices	CO 2	Understanding the characteristics of current flow in a bipolar junction transistor and MOSFET.
EI4-07	onic De	CO 3	Understand and utilize the mathematical models of semiconductor junctions and MOS transistors for circuits and systems.
Ø	Electre	CO 4	Analyze the characteristics of different electronic devices such as Amplifiers, LEDs, Solar cells, etc.
		CO 5	Theoretical as well as experimental understanding of Integrated circuit fabrication.

CO-PO Mapping:

Subject	Course Outcome s	РО 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10	PO 11	PO 12
	CO 1	3	1		2	1	1						
)7 nic es	CO 2	3	2	1			2						
Ctro ctro	CO 3	2	1		2		1	2					
Ble De	CO 4	3	1	1				2					
	CO 5	3	1	1	1	1							2
	3: \$	Strong	gly	2	2: Mo	derat	te		1	: We	ak		



SYLLABUS

2nd Year - III Semester: B.Tech. (Electronics Instrumentation & Control)

Lecture Plan:

Lecture	Content to be taught
NO.	
Lecture 1	Zero Lecture
Lecture 2	Introduction to Semiconductor Physics
Lecture 3	Introduction to Semiconductor Physics
Lecture 4	Introduction to Semiconductor Physics
Lecture 5	Review of Quantum Mechanics
Lecture 6	Electrons in periodic Lattices
Lecture 7	E-k diagrams
Lecture 8	Energy bands in intrinsic and extrinsic silicon
Lecture 9	Carrier transport: diffusion current, drift current, mobility and resistivity
Lecture 10	Sheet resistance and design of resistors
Lecture 11	Generation and recombination of carriers
Lecture 12	Poisson and continuity equation
Lecture 13	P-N junction characteristics and their I-V characteristics
Lecture 14	P-N junction characteristics and their I-V characteristics
Lecture 15	P-N junction small signal switching models
Lecture 16	P-N junction small signal switching models
Lecture 17	Avalanche breakdown
Lecture 18	Zener diode and Schottky diode
Lecture 19	Basics of Bipolar Junction Transistor
Lecture 20	I-V characteristics of BJT
Lecture 21	Ebers-Moll Model
Lecture 22	MOS capacitor



SYLLABUS

🦾 2 nd Year	- III Semester: B.Tech. (Electronics Instrumentation & Control)
Lecture 23	MOS capacitor
Lecture 24	C-V characteristics
Lecture 25	Basics of MOSFET
Lecture 26	Basics of MOSFET
Lecture 27	I-V characteristics of MOSFET
Lecture 28	Small signal models of MOS transistor
Lecture 29	Small signal models of MOS transistor
Lecture 30	Light Emitting Diode
Lecture 31	Photodiode and solar cell
Lecture 32	Basics of Integrated Circuits
Lecture 33	Advancement in Integrated Circuits
Lecture 34	Oxidation, diffusion and ion implantation
Lecture 35	Photolithography and etching
Lecture 36	Chemical vapor deposition
Lecture 37	Sputtering
Lecture 38	Twin-tub CMOS process
Lecture 39	Spill over class
Lecture 40	Spill over class

Content delivery method:

- 1. Chalk and Duster
- **2.** PPT
- 3. Hand-outs



SYLLABUS

2nd Year - III Semester: B.Tech. (Electronics Instrumentation & Control)

Sample assignments:

Assignment 1	Q1.	Investigates the input/output characteristics of various diodes?									
	Q2.	Investigate the applications of various diodes?									
	Q3.	A p-type sample of silicon has a resistivity of 5 Ω -cm.									
		In this sample, the hole mobility, μ_h , is 600 cm ² /V-s									
		and the electron mobility, μ_e , is 1600 cm ² /V-s. Ohmic									
		contacts are formed on the ends of the sample and a uniform electric field is imposed which results in a drift									
		 current density in the sample is 2 x 10³ A/cm². [1]. What are the hole and electron concentrations in this sample? 									
		[2]. What are the hole and electron drift velocities under these conditions?									
		[3]. What is the magnitude of the electric field?									
Assignment 2	01.	Discuss the applications of Ebers-Moll Model									
.	Q2.	Discuss different types of fabrication techniques.									
	Q 3.	Discuss various characteristics of CMOS transistor.									



SYLLABUS

2nd Year - III Semester: B.Tech. (Electronics Instrumentation & Control)

3EI4-21: Electronics Devices Lab

1 Credit

Max. Marks: 50 (IA:30, ETE:20)

0L:0T:2P

List of Experiments

Name of Experiment
Study the following devices: (a) Analog& digital multimeters (b) Function/ Signal generators (c) Regulated d. c. power supplies (constant voltage and constant current operations) (d) Study of analog and digital CRO, measurement of time period, amplitude, frequency & phase angle using Lissajous figures.
Plot V-I characteristic of P-N junction diode & calculate cut-in voltage, reverse Saturation current and static & dynamic resistances.
Plot the output waveform of half wave rectifier and effect of filters on waveform. Also calculate its ripple factor.
Study bridge rectifier and measure the effect of filter network on D.C. voltage output & ripple factor.
Plot and verify output waveforms of different clipper and clamper.
Plot V-I characteristic of Zener diode
Study of Zener diode as voltage regulator. Observe the effect of load changes and determine load limits of the voltage regulator
Plot input-output characteristics of BJT in CB, CC and CE configurations. Find their h-parameters.
Study of different biasing circuits of BJT amplifier and calculate its Q-point.
Plot frequency response of two stage RC coupled amplifier & calculate its bandwidth .
Plot input-output characteristics of field effect transistor and measure $I_{\rm dss} and \ V_{\rm p}.$
Plot frequency response curve for FET amplifier and calculate its gain bandwidth product.
Rajasthan Technical University, Vote



SYLLABUS

2nd Year - III Semester: B.Tech. (Electronics Instrumentation & Control)

Course Outcome:

Course Code	Cours e Name	Course Outcome	Details								
4-21		CO 1	Understand the characteristics of different Electronic Devices.								
	Lab	CO 2	Verify the rectifier circuits using diodes and implement them using hardware.								
	Devices	CO 3	Design various amplifiers like CE, CC, common source amplifiers and implement them using hardware and also observe their frequency responses								
3E	ctronic	CO 4	Understand the construction, operation and characteristics of JFET and MOSFET, which can be used in the design of amplifiers.								
	Ele	CO 5	Understand the need and requirements to obtain frequency response from a transistor so that Design of RF amplifiers and other high frequency amplifiers is feasible								

CO-PO Mapping:

Subject	Course Outcom es	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10	PO 11	PO 12
	CO 1	3	2	3	2	1							1
21 nic Lab	CO 2	2	3	1	3	3							2
SI4-2 ctro ices	CO 3	2	1	2	3	3							
3I Ele Dev	CO 4	3	2	3	2	2							1
	CO 5	3	2	1	2	2							
	3: 5	Strong	gly	2: Moderate				1: Weak					

SYLLABUS

2nd Year - III Semester: B.Tech. (Electronics Instrumentation & Control)

3EI4-22: Digital System Design Lab

Max. Marks: 50 (IA:30, ETE:20)

1 Credit

OL:OT:2P List of Experiments

S. No.	Name of Experiment
Part	A: Combinational Circuits
1.	To verify the truth tables of logic gates: AND, OR, NOR, NAND, NOR, Ex-OR and Ex-NOR
2.	To verify the truth table of OR, AND, NOR, Ex-OR, Ex-NOR logic gates realized using NAND & NOR gates.
3.	To realize an SOP and POS expression.
4.	To realize Half adder/ Subtractor& Full Adder/ Subtractor using NAND & NOR gates and to verify their truth tables
5.	To realize a 4-bit ripple adder/ Subtractor using basic Half adder/ Subtractor& basic Full Adder/ Subtractor.
6.	To design 4-to-1 multiplexer using basic gates and verify the truth table. Also verify the truth table of 8-to-1 multiplexer using IC
7.	To design 1-to-4 demultiplexer using basic gates and verify the truth table. Also to construct 1-to-8 demultiplexer using blocks of 1-to-4 demultiplexer
8.	To design 2x4 decoder using basic gates and verify the truth table. Also verify the truth table of 3x8 decoder using IC
9.	Design & Realize a combinational circuit that will accept a 2421 BCD code and drive a TIL -312 seven-segment display
Part	B: Sequential Circuits
10.	Using basic logic gates, realize the R-S, J-K and D-flip flops with and without clock signal and verify their truth table.
11.	Construct a divide by 2, 4 & 8 asynchronous counter. Construct a 4-bit binary counter and ring counter for a particular output pattern using D flip flop.
12.	Design and construct unidirectional shift register and verify the
13.	Design and construct BCD ripple counter and verify the function.
14.	Design and construct a 4 Bit Ring counter and verify the function
15.	Perform input/output operations on parallel in/Parallel out and Serial in/Serial out registers using clock. Also exercise loading only one of multiple values into the register using multiplexer.
Note	e: Minimum 6 experiments to be conducted from Part-A& 4 experiments to

be conducted from **Part-B.**





SYLLABUS

2nd Year - III Semester: B.Tech. (Electronics Instrumentation & Control)

Course Outcome:

Course Code	Cours e Name	Course Outcome	Details
		CO 1	
0	stem ,ab	CO 2	To minimize the complexity of digital logic circuits.
014-2	ıl Sys ign L	CO 3	To design and analyse combinational logic circuits.
3E	çita Jes	CO 4	To design and analyse sequential logic circuits.
	Dig	CO 5	Able to implement applications of combinational & sequential logic circuits.

CO-PO Mapping:

Subject	Course Outco mes	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10	PO 11	PO 12
g	CO 1	3	3	1									1
22 ster Lab	CO 2	3	3	2	1	1							1
014-2 1 Sy ign	CO 3	3	3	3	2	3	1						2
3E igita Des	CO 4	3	3	3	2	3	1						2
A	CO 5	3	3	3	3	3	3						3
3: Strongly 2: Moderate 1: Weak													

SYLLABUS

2nd Year - III Semester: B.Tech. (Electronics Instrumentation & Control)

3EI4-23: Signal Processing Lab

Max. Marks: 50 (IA:30, ETE:20)

1 Credit OL:OT:2P

List of Experiments

Sr.	Name of Experiment (Simulate using MATIAR environment)
No.	Name of Experiment (Simulate using MATLAB environment)
1	Generation of continuous and discrete elementary signals (periodic and
1.	non periodic)using mathematical expression.
2.	Generation of Continuous and Discrete Unit Step Signal.
2	Generation of Exponential and Ramp signals in Continuous & Discrete
э.	domain.
4.	Continuous and discrete time Convolution (using basic definition).
Б	Adding and subtracting two given signals. (Continuous as well as Discrete
5	signals)
6.	To generate uniform random numbers between (0, 1).
7.	To generate a random binary wave.
	To generate and verify random sequences with arbitrary distributions,
	means and variances for following:
8.	(a) Rayleigh distribution
	(b) Normal distributions: N(0,1).
	(c) Gaussion distributions: N (m, x)
9	To plot the probability density functions. Find mean and variance for the
9.	above distributions



SYLLABUS

2nd Year - III Semester: B.Tech. (Electronics Instrumentation & Control)

Course Outcome:

Course Code	Course Name	Course Outcom e	Details							
	; Lab	CO 1	Able to generate different Continuous and Discrete time signals.							
23	ssing	CO 2	Understand the basics of signals and different operations on signals.							
EI4-:	roce	CO 3	Develop simple algorithms for signal processing and test them using MATLAB							
C	nal P	CO 4	Able to generate the random signals having different distributions, mean and variance.							
	Sig	CO 5	Design and conduct experiments, interpret an analyse data and report results.							

CO-PO Mapping:

Subject	Course Outcom es	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10	PO 11	PO 12
ng	CO 1	2		1		2							
3 essi	CO 2	3		1									
)14-2 Proc Lab	CO 3	1	2	3	1	3							
3E nal	CO 4	2	1	1		2							
Sig	CO 5	1	1	2	2	2							
	3: Strongly 2: Moderate 1: Weak												

RAJASTHAN TECHNICAL UNIVERSITY, KOTA Syllabus



1 Credit

2nd Year - III Semester: B.Tech. (Electronics Instrumentation & Control)

3EI3-24: Computer Programming Lab-I

Max. Marks: 50 (IA:30, ETE:20)

0L:C	DT:2P
1.	Write a simple C program on a 32 bit compiler to understand the concept of array storage, size of a word. The program shall be written illustrating the concept of row major and column major storage. Find the address of element and verify it with the theoretical value. Program may be written for arrays upto 4-dimensions.
2.	Simulate a stack, queue, circular queue and dequeue using a one dimensional array as storage element. The program should implement the basic addition, deletion and traversal operations.
3.	Represent a 2-variable polynomial using array. Use this representation to implement addition of polynomials.
4.	Represent a sparse matrix using array. Implement addition and transposition operations using the representation.
5.	Implement singly, doubly and circularly connected linked lists illustrating operations like addition at different locations, deletion from specified locations and traversal.
6.	Repeat exercises 2, 3 & 4 with linked structures.
7.	Implementation of binary tree with operations like addition, deletion, traversal.
8.	Depth first and breadth first traversal of graphs represented using adjacency matrix and list.
9.	Implementation of binary search in arrays and on linked Binary Search Tree.
10.	Implementation of insertion, quick, heap, topological and bubble sorting algorithms.



SYLLABUS

2nd Year - IV Semester: B.Tech. (Electronics Instrumentation & Control)

4EI2-01: Advance Engineering Mathematics-II

Credit: 3 3L+0T+0P Max. Marks: 150(IA:30, ETE:120) End Term Exam: 3 Hours

SN	Contents	Hours
1	Introduction: Objective, scope and outcome of the course.	1
2	Complex Variable – Differentiation: Differentiation, Cauchy-Riemann equations, analytic functions, harmonic functions, finding harmonic conjugate; elementary analytic functions (exponential, trigonometric, logarithm) and their properties; Conformal mappings, Mobius transformations and their properties.	7
3	Complex Variable - Integration: Contour integrals, Cauchy-Goursat theorem (without proof), Cauchy Integral formula (without proof), Liouville's theorem and Maximum-Modulus theorem (without proof); Taylor's series, zeros of analytic functions, singularities, Laurent's series; Residues, Cauchy Residue theorem (without proof).	8
4	Applications of complex integration by residues: Evaluation of definite integral involving sine and cosine. Evaluation of certain improper integrals.	4
5	Special Functions: Legendre's function, Rodrigues formula, generating function, Simple recurrence relations, orthogonal property.Bessel's functions of first and second kind, generating function, simple recurrence relations, orthogonal property.	10
6	Linear Algebra: Vector Spaces, subspaces, Linear independence, basis and dimension, Inner product spaces, Orthogonality, Gram Schmidt orthogonalization, characteristic polynomial, minimal polynomial, positive definite matrices and canonical forms, QR decomposition.	10
	Total	40



SYLLABUS

2nd Year - IV Semester: B.Tech. (Electronics Instrumentation & Control)

4EI1-03/3EI1-03: Managerial Economics And Financial Accounting

2 Credit 2L:0T:0P

Max. Marks: 100 (IA:20, ETE:80) End Term Exam: 2 Hours

SN	Contents	Hours
1	Introduction: Objective, scope and outcome of the course.	1
2	Basic economic concepts- Meaning, nature and scope of economics, deductive vs inductive methods, static and dynamics, Economic problems: scarcity and choice, circular flow of economic activity, national income-concepts and measurement.	3
3	Demand and Supply analysis- Demand-types of demand, determinants of demand, demand function, elasticity of demand, demand forecasting –purpose, determinants and methods, Supply-determinants of supply, supply function, elasticity of supply.	5
4	Production and Cost analysis- Theory of production- production function, law of variable proportions, laws of returns to scale, production optimization, least cost combination of inputs, isoquants. Cost concepts-explicit and implicit cost, fixed and variable cost, opportunity cost, sunk costs, cost function, cost curves, cost and output decisions, cost estimation.	5
5	Market structure and pricing theory- Perfect competition, Monopoly, Monopolistic competition, Oligopoly.	4
6	Financial statement analysis- Balance sheet and related concepts, profit and loss statement and related concepts, financial ratio analysis, cash-flow analysis, funds-flow analysis, comparative financial statement, analysis and interpretation of financial statements, capital budgeting techniques.	8
	Total	26



SYLLABUS

2nd Year - IV Semester: B.Tech. (Electronics Instrumentation & Control)

4EI1-02/3EI1-02: Technical Communication

2 Credit 2L:0T:0P

Max. Marks: 100 (IA:20, ETE:80) End Term Exam: 2 Hours

SN	Contents	Hours
1	Introduction: Objective, scope and outcome of the course.	1
2	Introduction to Technical Communication- Definition of technical communication, Aspects of technical communication, forms of technical communication, importance of technical communication, technical communication skills (Listening, speaking, writing, reading writing), linguistic ability, style in technical communication.	3
3	Comprehension of Technical Materials/Texts and Information Design & development- Reading of technical texts, Readingand comprehending instructions and technical manuals, Interpreting and summarizing technical texts, Note-making. Introduction of different kinds of technical documents, Information collection, factors affecting information and document design, Strategies for organization, Information design and writing for print and online media.	6
4	Technical Writing, Grammar and Editing - Technical writing process, forms of technical discourse, Writing, drafts and revising, Basics of grammar, common error in writing and speaking, Study of advanced grammar, Editing strategies to achieve appropriate technical style, Introduction to advanced technical communication. Planning, drafting and writing Official Notes, Letters, E-mail, Resume, Job Application, Minutes of Meetings.	8
5	Advanced Technical Writing- Technical Reports, types of technical reports, Characteristics and formats and structure of technical reports. Technical Project Proposals, types of technical proposals, Characteristics and formats and structure of technical proposals. Technical Articles, types of technical articles, Writing strategies, structure and formats of technical articles.	8
	Total	26



SYLLABUS

2nd Year - IV Semester: B.Tech. (Electronics Instrumentation & Control)

4EI4-04: Analog Circuits

Credit: 3 3L+0T+0P

Max. Marks: 150(IA:30, ETE:120) End Term Exam: 3 Hours

SN	Contents	Hours
1	Introduction: Objective, scope and outcome of the course.	1
2	Diode Circuits, Amplifier models: Voltage amplifier, current amplifier, trans-conductance amplifier and trans-resistance amplifier. Biasing schemes for BJT and FET amplifiers, bias stability, various configurations (such as CE/CS, CB/CG, CC/CD) and their features, small signal analysis, low frequency transistor models, estimation of voltage gain, input resistance, output resistance etc., design procedure for particular specifications, low frequency analysis of multistage amplifiers.	8
3	High frequency transistor models, frequency response of single stage and multistage amplifiers, cascode amplifier. Various classes of operation (Class A, B, AB, C etc.), their power efficiency and linearity issues. Feedback topologies: Voltage series, current series, voltage shunt, current shunt, effect of feedback on gain, bandwidth etc., calculation with practical circuits, concept of stability, gain margin and phase margin.	8
4	Oscillators: Review of the basic concept, Barkhausen criterion, RC oscillators (phase shift, Wien bridge etc.), LC oscillators (Hartley, Colpitt, Clapp etc.), non-sinusoidal oscillators. Current mirror: Basic topology and its variants, V-I characteristics, output resistance and minimum sustainable voltage (VON), maximum usable load. Differential amplifier: Basic structure and principle of operation, calculation of differential gain, common mode gain, CMRR and ICMR. OP-AMP design: design of differential amplifier for a given specification, design of gain stages and output stages, compensation.	8
5	OP-AMP applications: review of inverting and non-inverting amplifiers, integrator and differentiator, summing amplifier, precision rectifier, Schmitt trigger and its applications. Active filters: Low pass, high pass, band pass and band stop, design guidelines.	8
6	Digital-to-analog converters (DAC): Weighted resistor, R-2R ladder, resistor string etc. Analog to digital converters (ADC): Single slope, dual slope, successive approximation, flash etc. Switched capacitor circuits: Basic concept, practical configurations, application in amplifier, integrator, ADC etc.	7
	Total	40



SYLLABUS

2nd Year - IV Semester: B.Tech. (Electronics Instrumentation & Control)

Course Outcome:

Course	Course	Course	Details					
Code	Name	Outcome	Details					
		CO 1	Understand the characteristics of diodes and transistors					
04	ircuits	CO 2	Design and analyze various rectifier and amplifier circuits					
EI4-	og C	CO 3	Design sinusoidal and non-sinusoidal oscillators					
4	Anal	CO 4	Understand the functioning of OP-AMP and design OP-AMP based circuits					
		CO 5	Understanding the designing of ADCs and DACs					

CO-PO Mapping:

Subject	Course Outcomes	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10	PO 11	PO 12
	CO 1	3		1	1	2							
4 reuits	CO 2	1	1	2		1							
EI4-0 g Cin	CO 3	3	1		1								
41 Analo	CO 4	2				2							
ł	CO 5	2	3		2								
		3: S	trongl	y		2: Mo	derate)	1:	Weal	K		



Lecture Plan:

Lecture No.	Content to be taught
Lecture 1	Zero Lecture
Lecture 2	Diode Circuits and Amplifier models
Lecture 3	Voltage amplifier, current amplifier, trans-conductance amplifier and trans-resistance amplifier
Lecture 4	Biasing schemes for BJT and FET amplifiers
Lecture 5	Bias stability in various configurations such as CE/CS, CB/CG, CC/CD
Lecture 6	Small signal analysis of BJT and FET
Lecture 7	low frequency transistor models
Lecture 8	Estimation of voltage gain, input resistance, output resistance etc.
Lecture 9	Design procedure for particular specifications, low frequency analysis of multistage amplifiers.
Lecture 10	High frequency transistor models
Lecture 11	frequency response of single stage and multistage amplifiers
Lecture 12	Cascode Amplifier
Lecture 13	Various classes of operation (Class A, B, AB, C etc.), their power efficiency and linearity issues
Lecture 14	Feedback topologies: Voltage series, current series, voltage shunt, current shunt
Lecture 15	Effect of feedback on gain, bandwidth etc.,
Lecture 16	Calculation with practical circuits
Lecture 17	Concept of stability, gain margin and phase margin.
Lecture 18	Basics of oscillator
Lecture 19	Barkhausen criterion, RC oscillators (phase shift, Wien bridge etc.)
Lecture 20	LC oscillators (Hartley, Colpitt, Clapp etc.)
Lecture 21	Non-sinusoidal oscillators. Current mirror: Basic topology and its variants,
L	Office of Deep Academic Afficia



RAJASTHAN TECHNICAL UNIVERSITY, KOTA SYLLABUS

2nd Year - IV Semester: B.Tech. (Electronics Instrumentation & Control)

Lecture 22	V-I characteristics, output resistance and minimum sustainable voltage (VON), maximum usable load.
Lecture 23	Differential amplifier: Basic structure and principle of operation, calculation of differential gain, common mode gain, CMRR and ICMR.
Lecture 24	OP-AMP design: design of differential amplifier for a given specification
Lecture 25	Design of gain stages and output stages, compensation
Lecture 26	OP-AMP applications: review of inverting and non-inverting amplifiers
Lecture 27	Integrator and differentiator, summing amplifier
Lecture 28	Precision rectifier, Schmitt trigger and its applications
Lecture 29	Active filters: Low pass, high pass
Lecture 30	Band pass and band stop Filters
Lecture 31	Filter Design guidelines
Lecture 32	Digital-to-analog converters (DAC): Weighted resistor, R-2R ladder, resistor string etc
Lecture 33	Analog to digital converters (ADC): Single slope, dual slope
Lecture 34	successive approximation, flash TYPE ADC
Lecture 35	Switched capacitor circuits: Basic concept
Lecture 36	Switched capacitor circuits: practical configurations
Lecture 37	Switched capacitor circuits: applications
Lecture 38	Spill over classes
Lecture 39	Spill over classes
Lecture 40	Spill over classes

Content delivery method:

- 1. Chalk and Duster
- **2.** PPT
- 3. Hand-outs



Sample assignments:

Assignment 1	Q1. Assume that a silicon transistor with $\beta = 50$, $V_{BEactive} = 0.7$ V, $V_{CC} = 15$ V
_	and $R_{c}=10K$ is used in the Fig.1.It is desired to establish a Q-point at
	$V_{CE}=7.5$ V and $I_{C}=5$ mA and stability factor S \leq 5.Find Re,R ₁ and R ₂ .
	Q2. In the Darlington stage shown in Fig.2 , $V_{cc}=15V$, $\beta_1=50$,
	$\beta_2 = \frac{1}{5}, \forall_{BE} = 0.7, R_C = \frac{1}{50} \Omega$ and $R_E = 100 \Omega$. If at the quiescent point
	$V_{CE2}=6V$ determine the value of R.
	Rc
	R
	Vi Cin Pat
	Q3. For the amplifier shown in Fig.3 using a transistor whose parameters
	are $h_{ie}=1100, h_{re}=2.5\times10^{-4}, h_{fe}=50, h_{oe}=24\mu A/V$. Find A_{I}, A_{V}, A_{VS} and R_{i} .



SYLLABUS

2nd Year - IV Semester: B.Tech. (Electronics Instrumentation & Control)



SYLLABUS

2nd Year - IV Semester: B.Tech. (Electronics Instrumentation & Control)

4EI4-05: Microcontrollers

Credit: 3 3L+0T+0P Max. Marks: 150(IA:30, ETE:120) End Term Exam: 3 Hours

SN	Contents	Hours
1	Introduction: Objective, scope and outcome of the course.	1
2	Overview of microcomputer systems and their building blocks, memory interfacing, concepts of interrupts and Direct Memory Access, instruction sets of microprocessors (with examples of 8085 and 8086);	10
3	Interfacing with peripherals - timer, serial I/O, parallel I/O, A/D and D/A converters; Arithmetic Coprocessors; System level interfacing design;	8
4	Concepts of virtual memory, Cache memory, Advanced coprocessor Architectures- 286, 486, Pentium; Microcontrollers: 8051 systems,	10
5	Introduction to RISC processors; ARM microcontrollers interface designs.	11
	Total	40

Course Outcome:

Course Code	Course Name	Course Outcome	Details
		CO 1	Develop assembly language programming skills.
5	collers	CO 2	Able to build interfacing of peripherals like, I/O, A/D, D/A, timer etc.
EI4-0	conti	CO 3	Develop systems using different microcontrollers.
4	licro	CO 4	Explain the concept of memory organization.
	A	CO 5	Understand RSIC processors and design ARM microcontroller based systems.



CO-PO Mapping:

Subject	Course Outcomes	РО 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10	PO 11	PO 12
rs	CO 1			3	1								
rolle	CO 2			3		1							
EI04 ocon1	CO 3	1	2	3									
4 Micr	CO 4	3	2	1									
02	CO 5			3	2	1							
	•	3: Stro	ongly	•	2:	Mode	rate		1: W	Veak			

Lecture Plan:

Lecture No.	Content to be taught
Lecture 1	Zero Lecture
Lecture 2	Overview of microcomputer systems and their building blocks
Lecture 3	Overview of microcomputer systems and their building blocks
Lecture 4	Memory interfacing
Lecture 5	Memory interfacing
Lecture 6	Concepts of interrupts
Lecture 7	Direct Memory Access
Lecture 8	Direct Memory Access
Lecture 9	Instruction sets of microprocessors (with examples of 8085 and 8086)
Lecture 10	Instruction sets of microprocessors (with examples of 8085 and 8086)
Lecture 11	Instruction sets of microprocessors (with examples of 8085 and 8086)
Lecture 12	Instruction sets of microprocessors (with examples of 8085 and 8086)
Lecture 13	Interfacing with peripherals Office of Dean Academic Affair
L	Rajasthan Technical University, I



Lecture 14	Timer
Lecture 15	Serial I/O
Lecture 16	Parallel I/O
Lecture 17	A/D and D/A converters;
Lecture 18	A/D and D/A converters
Lecture 19	Arithmetic Coprocessors
Lecture 20	System level interfacing design
Lecture 21	Concepts of virtual memory, Cache memory
Lecture 22	Concepts of virtual memory, Cache memory
Lecture 23	Advanced coprocessor Architectures- 286, 486, Pentium
Lecture 24	Advanced coprocessor Architectures- 286, 486, Pentium
Lecture 25	Advanced coprocessor Architectures- 286, 486, Pentium
Lecture 26	Microcontrollers: 8051 systems,
Lecture 27	Microcontrollers: 8051 systems,
Lecture 28	Microcontrollers: 8051 systems,
Lecture 29	Microcontrollers: 8051 systems,
Lecture 30	Microcontrollers: 8051 systems,
Lecture 31	Introduction to RISC processors
Lecture 32	Introduction to RISC processors
Lecture 33	Introduction to RISC processors
Lecture 34	ARM microcontrollers interface designs
Lecture 35	ARM microcontrollers interface designs
Lecture 36	ARM microcontrollers interface designs
Lecture 37	ARM microcontrollers interface designs
Lecture 38	ARM microcontrollers interface designs
Lecture 39	Spill Over Classes
Lecture 40	Spill Over Classes



Content delivery method:

- **1.** Chalk and Duster
- **2.** PPT
- 3. Hand-outs

Assignments:

Assignment 1	Q1. Compare between microprocessor & microcontroller based on no. of instructions used, registers, memory and applications.											
	Q2. Interface external program memory with 8051 & explain how the data is transfer.											
	Q3. List the I/O ports of microcontroller 8051. Explain their alternat function?											
Assignment 2Q1. Explain RISC and CISC?												
	 Q2. Without using MUL instruction, perform multiplication operation on any two operands, with both of them being: a. Positive numbers b. One positive and other negative number 											
	c. Both negative numbers Verify the values computed.											
	Q3. Can you brief up the evolution of ARM architecture?											

SYLLABUS

2nd Year - IV Semester: B.Tech. (Electronics Instrumentation & Control)

4EI3-06: Measurement & Instrumentation

Credit: 3 3L+0T+0P

Max. Marks: 150(IA:30, ETE:120) End Term Exam: 3 Hours

SN	Contents	Hours
1	Introduction: Objective, scope and outcome of the course.	1
2	THEORY OF ERRORS - Accuracy & precision, Repeatability, Limits of errors, Systematic & random errors, Modeling of errors, Probable error & standard deviation, Gaussian error analysis, Combination of errors.	8
3	Measuring Instruments - Moving coil, moving iron, Electrodynamic and induction instruments-construction, operation, torque equation and errors. Applications of instruments for measurement of current, voltage, single-phase power and single-phase energy. Errors in wattmeter and energy meter and their compensation and adjustment. Testing and calibration of single-phase energy meter by phantom loading. Electronic Voltmeter, Electronic Multimeters, Digital Voltmeter, and Component Measuring Instruments: Q meter, Vector Impedance meter	8
4	Polyphase Metering - Blondel's Theorem for n-phase, p-wire system. Measurement of power and reactive kVA in 3-phase balanced and unbalanced systems: One-wattmeter, two-wattmeter and three-wattmeter methods. 3-phase induction type energy meter. Instrument Transformers: Construction and operation of current and potential transformers. Ratio and phase angle errors and their minimization. Effect of variation of power factor, secondary burden and frequency on errors.Testing of CTs and PTs. Applications of CTs and PTs for the measurement of current, voltage, power and energy.	7
5	Measurement of Resistances - Classification of resistance. Measurement of medium resistances– ammeter and voltmeter method, substitution method, Wheatstone bridge method. Measurement of low resistances – Potentiometer method and Kelvin's double bridge method. Measurement of high resistance: Price's Guard-wire method. Measurement of earth resistance.	8
6	AC Bridges - Generalized treatment of four-arm AC bridges. Sources and detectors. Maxwell's bridge, Hay's bridge and Anderson bridge for self-inductance measurement. Heaviside's bridge for mutual inductance measurement.De Sauty Bridge for capacitance measurement.Wien's bridge for capacitance and frequency measurements.Sources of error in bridge measurements and precautions.Screening of bridge components.Wagner earth device.	8
	Total	40

SYLLABUS

2nd Year - IV Semester: B.Tech. (Electronics Instrumentation & Control)

4EI4-07: Analog and Digital Communication

Credit: 3 3L+0T+0P

Max. Marks: 150(IA:30, ETE:120) End Term Exam: 3 Hours

SN	Contents	Hours
1	Introduction: Objective, scope and outcome of the course.	1
2	Review of signals and systems, Frequency domain representation of signals, Principles of AmplitudeModulation Systems- DSB, SSB and VSB modulations. Angle Modulation, Representation of FM and PM signals, Spectral characteristics of angle modulated signals.	8
3	Review of probability and random process. Gaussian and white noise characteristics, Noise in amplitude modulation systems, Noise in Frequency modulation systems. Pre-emphasis and Deemphasis, Threshold effect in angle modulation.	7
4	Pulse modulation. Sampling process. Pulse Amplitude and Pulse code modulation (PCM), Differential pulse code modulation. Delta modulation, Noise considerations in PCM, Time Division multiplexing, Digital Multiplexers.	8
5	Elements of Detection Theory, Optimum detection of signals in noise, Coherent communication with waveforms- Probability of Error evaluations. BasebandPulse Transmission- Inter symbol Interference and Nyquist criterion. Pass band Digital Modulation schemes- Phase Shift Keying, Frequency Shift Keying, Quadrature Amplitude Modulation, Continuous Phase Modulation and Minimum Shift Keying.	8
6	Digital Modulation tradeoffs. Optimum demodulation of digital signals over band- limitedchannels- Maximum likelihood sequence detection (Viterbi receiver). Equalization Techniques. Synchronization and Carrier Recovery for Digital modulation.	8
	Total	40



Course Outcome:

Course Code	Course Name	Course Outcome	Details
		CO 1	Analyze and compare different analog modulation schemes for their efficiency and bandwidth
	ınd Digital unication	CO 2	Analyze the behavior of a communication system in presence of noise
[4-07		CO 3	Investigate pulsed modulation system and analyze their system performance
4EI	vnalog a Comm	CO 4	Analyze different digital modulation schemes and can compute the bit error performance
	A	CO 5	Design a communication system comprised of both analog and digital modulation techniques

CO-PO Mapping:

Subject	•	Course Outcomes	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10	PO 11	PO 12
I		CO 1	3	3		3		1				1		
7 Digita	nalog & Digita Communication	CO 2	3	2		3		1						
EI4-0 g & I		CO 3	3	2		3		2						
4] nalog		CO 4	3	3		3		2				1		
A)	CO 5	3	2	3	3		3			2	2		
			3: Stro	ongly		2:	Mode	rate	•	1: V	Veak		•	•

Content delivery method:

- **1.** Chalk and Duster
- **2.** PPT

RAJASTHAN TECHNICAL UNIVERSITY, KOTA SYLLABUS 2nd Year - IV Semester: B.Tech. (Electronics Instrumentation & Control)

Lecture Plan:

Lecture No.	Content to be taught
Lecture 1	Introduction to the COURSE
Lecture 2	Review of signals and systems, Frequency domain representation of signals
Lecture 3	Principles of Amplitude Modulation Systems- DSB, SSB and VSB modulations
Lecture 4	Principles of Amplitude Modulation Systems- DSB, SSB and VSB modulations
Lecture 5	Principles of Amplitude Modulation Systems- DSB, SSB and VSB modulations
Lecture 6	Angle Modulation, Representation of FM and PM signals
Lecture 7	Angle Modulation, Representation of FM and PM signals
Lecture 8	Spectral characteristics of angle modulated signals.
Lecture 9	Review of probability and random process
Lecture 10	Review of probability and random process
Lecture 11	Noise in amplitude modulation systems
Lecture 12	Noise in amplitude modulation systems
Lecture 13	Noise in Frequency modulation systems
Lecture 14	Pre-emphasis and Deemphasis
Lecture 15	Threshold effect in angle modulation
Lecture 16	Pulse modulation. Sampling
Lecture 17	Pulse Amplitude and Pulse code modulation (PCM)
Lecture 18	Pulse Amplitude and Pulse code modulation (PCM)
Lecture 19	Differential pulse code modulation
Lecture 20	Delta modulation
Lecture 21	Noise considerations in PCM
Lecture 22	Time Division multiplexing, Digital Multiplexers
Lecture 23	Elements of Detection Theory
Lecture 24	Optimum detection of signals in noise
Lecture 25	Coherent communication with waveforms- Probability of Error evaluations Academic Affairs
	Rajasthan Technical University, Ko



Lecture 26	Coherent communication with waveforms- Probability of Error evaluations
Lecture 27	Baseband Pulse Transmission- Inter symbol Interference and Nyquist criterion
Lecture 28	Baseband Pulse Transmission- Inter symbol Interference and Nyquist criterion
Lecture 29	Pass band Digital Modulation schemes
Lecture 30	Phase Shift Keying
Lecture 31	Frequency Shift Keying
Lecture 32	Quadrature Amplitude Modulation
Lecture 33	Continuous Phase Modulation and Minimum Shift Keying.
Lecture 34	Digital Modulation tradeoffs
Lecture 35	Optimum demodulation of digital signals over band-limited channels
Lecture 36	Optimum demodulation of digital signals over band-limited channels
Lecture 37	Maximum likelihood sequence detection (Viterbi receiver)
Lecture 38	Equalization Techniques
Lecture 39	Synchronization and Carrier Recovery for Digital modulation
Lecture 40	Synchronization and Carrier Recovery for Digital modulation

SYLLABUS

SYLLABUS 2nd Year - IV Semester: B.Tech. (Electronics Instrumentation & Control)

Assignments:

Assignment 1	Q1. Design Modulator and Demodulator of SSB-SC Modulation based on its mathematical expression.
	Q2. Derive the figure of merit in a) FM Receiver b) PM Receiver
	Q3. A Carrier signal $c(t) = 20 \cos (2\pi 10^6 t)$ is modulated by a message signal having three frequencies 5 KHz, 10 KHz & 20 KHz. The corresponding modulation indexes are 0.4, 0.5 & 0.6. Sketch the spectrum. Calculate bandwidth, power and efficiency.
Assignment 2	Q1. Derive the expression for probability of error in ASK, FSK and PSK systems and compare them.
	Q2. With block diagrams explain about DPCM & DM. also compare them.
	 Q3. A message signal m(t) = 4 cos (2π10³t) is sampled at nyquist rate and transmitted through a channel using 3-bit PCM system. i. Calculate all the parameters of the PCM. ii. If the sampled values are 3.8, 2.1, 0.5, -1.7, -3.2 & -4 then determine the quantizer output, encoder output and quantization error per each sample. iii. Sketch the transfer characteristics of the quantizer.

SYLLABUS

2nd Year - IV Semester: B.Tech. (Electronics Instrumentation & Control)

4EI4-21: Analog and Digital Communication Lab

Credit: 1.5 0L+0T+3P Max. Marks: 75(IA:45, ETE:30)

Sr. No.	Name of Experiment
1.	Observe the Amplitude modulated wave form & measure modulation index and demodulation of AM signal.
2.	Harmonic analysis of Amplitude Modulated wave form.
3.	Generation & Demodulation of DSB – SC signal.
4.	Modulate a sinusoidal signal with high frequency carrier to obtain FM signal and demodulation of the FM signal.
5.	Verification of Sampling Theorem.
6.	To study & observe the operation of a super heterodyne receiver.
7.	PAM, PWM & PPM: Modulation and demodulation.
8.	To observe the transmission of four signals over a single channel using TDM-PAM method.
9.	To study the PCM modulation & demodulation and study the effect of channel like attenuation, noise in between modulator & demodulator through the experimental setup.
10.	To study the 4 channel PCM multiplexing & de-multiplexing in telephony system.
11.	To study the Delta & Adaptive delta modulation & demodulation and also study the effect of channel like attenuation, noise in between modulator & demodulator through the experimental setup.
12.	To perform the experiment of generation and study the various data formatting schemes (Unipolar, Bipolar, Manchester, AMI etc.)
13.	To perform the experiment of generation and detection of ASK, FSK, BPSK, DBPSK signals with variable length data pattern.

RAJASTHAN TECHNICAL UNIVERSITY, KOTA SYLLABUS 2nd Year - IV Semester: B.Tech. (Electronics Instrumentation & Control)

Course Outcome:

Course	Course	Course	Detaile						
Code	Name Outcome Details								
		CO 1	Understand different analog modulation schemes and evaluate modulation index						
tE14-21	igital on Lab	CO 2	Able to understand the principle of superhetrodyne receiver						
	g and D unicatio	CO 3	Develop time division multiplexing concepts in real time applications						
7	Analo Comm	CO 4	Develop and able to comprehend different data formatting schemes						
		CO 5	Comprehend and analyze the concepts of different digital modulation techniques in communication.						

CO-PO Mapping:

	Subject	Course Outcomes	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10	PO 11	PO 12
	alog and Digital nmunication Lab	CO 1	3	2		1								
1		CO 2	3	2	1									
E I4-2		CO 3	3	3	2	2	1							
. 41		CO 4	3	3	2	2	1							
.	AI Coi	CO 5	3	3	2	2	1							
			3: Str	ongly	•	2:	Mode	rate	•	1: V	Veak	•	•	•

SYLLABUS

2nd Year - IV Semester: B.Tech. (Electronics Instrumentation & Control)

4EI4-22: Analog Circuits Lab

Credit: 1.5 0L+0T+3P

Max. Marks: 75(IA:45, ETE:30)

Sr. No.	Name of Experiment
1.	Study and implementation of Voltage Series and Current Series Negative Feedback Amplifier.
2.	Study and implementation of Voltage Shunt and Current Shunt Negative Feedback Amplifier.
3.	Plot frequency response of BJT amplifier with and without feedback in the emitter circuit and calculate bandwidth, gain bandwidth product with and without negative feedback.
4.	Study and implementation of series and shunt voltage regulators and calculate line regulation and ripple factor.
5.	Plot and study the characteristics of small signal amplifier using FET.
6.	Study and implementation of push pull amplifier. Measure variation of output power & distortion with load and calculate the efficiency.
7.	Study and implementation of Wein bridge oscillator and observe the effect of variation in oscillator frequency.
8.	Study and implementation of transistor phase shift oscillator and observe the effect of variation in R & C on oscillator frequency and compare with theoretical value.
9.	Study and implementation of the following oscillators and observe the effect of variation of capacitance on oscillator frequency: (a) Hartley (b) Colpitts.
10.	Study and implementation of the Inverting And Non-Inverting Operational Amplifier.
11.	Study and implementation of Summing, Scaling And Averaging of Operational Amplifier
12.	Implementation of active filters using OPAMP.

RAJASTHAN TECHNICAL UNIVERSITY, KOTA SYLLABUS 2nd Year - IV Semester: B.Tech. (Electronics Instrumentation & Control)

Course Outcome:

Course	Course	Course	Deteile
Code	Name	Outcome	Details
		CO 1	Discuss and observe the operation of a bipolar junction transistor and field-effect transistor in different region of operations.
	Analog Circuits Lab	CO 2	Analyze and design of transistor Amplifier and Oscillators. Importance of negative feedback.
4EI4-22		CO 3	Analyze the frequency response of amplifiers and operational amplifier circuits. Develop an intuition for analog circuit behavior in both linear and nonlinear operation.
		CO 4	Design op-amps for specific gain, speed, or switching performance. Compensate operational amplifiers for stability.
		CO 5	Design and conduct experiments, interpret and analyze data, and report results.

CO-PO Mapping:

Subject	Course Outcomes	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10	PO 11	PO 12
ab	CO 1	3	2	1	2	2							
2 iits L	CO 2	2	3	1	2	3							
EI4-2 Circu	CO 3	1	3	2	3	2							
4] alog	CO 4	1	2	3	2	3							
An	CO 5	1	2	3	3	3							
3: Strongly						Mode	rate		1: V	Veak			

SYLLABUS

SYLLABUS 2nd Year - IV Semester: B.Tech. (Electronics Instrumentation & Control)

4EI4-23: Microcontrollers Lab

Credit: 1.5 0L+0T+3P Max. Marks: 75(IA:45, ETE:30)

Sr. No.	Name of Experiment
Follo	wing exercises has to be Performed on 8085
	Write a program for
1.	1.1 Multiplication of two 8 bit numbers
	1.2 Division of two 8 bit numbers
2.	Write a program to arrange a set of data in Ascending and Descending order.
3.	Write a program to find Factorial of a given number.
	Write a program to generate a Software Delay.
4.	4.1 Using a Register
	4.2 Using a Register Pair
8085	Interfacing Programs
5.	5.1 Write a program to Interface ADC with 8085.
	5.2 Write a program to interface Temperature measurement module with 8085.
6.	Write a program to interface Keyboard with 8085.
7.	Write a program to interface DC Motor and stepper motor with 8085.
Follo	wing exercises has to be Performed on 8051
8.	Write a program to convert a given Hex number to Decimal.
9.	Write a program to find numbers of even numbers and odd numbersamong 10 Numbers.
10.	Write a program to find Largest and Smallest Numbers among 10 Numbers.
11.	11.1 To study how to generate delay with timer and loop.
	11.2 Write a program to generate a signal on output pin using timer.
8051	Interfacing Programs
12	12.1 Write a program to interface Seven Segment Display with 8051.
	12.2 Write a program to interface LCD with 8051.
13	Write a program for Traffic light Control using 8051.
14	Write a program for Elevator Control using 8051.

RAJASTHAN TECHNICAL UNIVERSITY, KOTA SYLLABUS

SYLLABUS 2nd Year - IV Semester: B.Tech. (Electronics Instrumentation & Control)

Course Outcome:

Course	Course	Course	Details							
Code	Name	Outcome	Details							
	CO1 Develop skills related to assembly level programming of microprocessors and microcontroller.									
	llers La	CO 2	Interpret the basic knowledge of microprocessor and microcontroller interfacing, delay generation, waveform generation and Interrupts.							
	contro	Interfacing the external devices to the microcontroller and microprocessor to solve real time problems.								
-23	licroc	CO 4	Illustrate functions of various general purpose interfacing devices.							
4EI4	2	CO 5	Develop a simple microcontroller and microprocessor based systems							

CO-PO Mapping:

Subject	Course Outcomes	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10	PO 11	PO 12
da	CO 1	2	1	2	1	3							
3 lers I	CO 2	3	2	1	2	1							
EI4-2 ntroll	CO 3	1	1	3	1	3							
41 rocoi	CO 4	2	2	1									
Mic	CO 5	1	1	3	2	2		2					
	•	3: Stre	ongly	•	2:	Mode	rate	•	1: V	Veak		•	•

SYLLABUS

2nd Year - IV Semester: B.Tech. (Electronics Instrumentation & Control)

4EI4-24: Measurement & Instrumentation Lab

Max. Marks: 75(IA:45, ETE:30)

Credit: 1.5 0L+0T+3P

Sr.	Contents
No.	
1.	Measure the low resistance by Kelvin's double bridge
2.	Calibrate an ammeter using D.C. slide wire potentiometer.
3.	Calibrate a wattmeter using Crompton's potentiometer
4.	Measure the power in 3-phase star connected load by two-wattmeter method at different values of load
	power factor.
5.	Calibrate a single-phase energy meter (Analog and Digital) by phantom loading at different power factor
	by
	a) Phase shifting transformer
	b) Auto transformer.
6.	Measure earth resistance using fall of potential method
7.	Plot the V-I characteristics of a solar panel.
8.	Measure low resistance using Crompton's potentiometer
9.	Measure unknown inductance using Anderson's bridge.
10.	Measure unknown frequency using Wein's Bridge
11.	Measure unknown capacitance using DeSauty Bridge.
12.	a) To see the burden effect on the performance of CT
	b) To measure phase angle and ratio error of CT.

RAJASTHAN TECHNICAL UNIVERSITY, KOTA SYLLABUS 2nd Year - IV Semester: B.Tech. (Electronics Instrumentation & Control)

Course Outcome:

Cour se Code	Course Name	Course Outcome	Details								
		CO 1	Understanding of the fundamentals of Electronic								
			Instrumentation. Explain and identify measuring								
	& Lab		instruments.								
		CO 2	Able to measure resistance, inductance and capacitance								
4	ent ion		by various methods.								
4-2	eme	CO 3	Design an instrumentation system that meets desired								
EL	urq		specifications and requirements.								
4	Meas	CO 4	Design and conduct experiments, interpret and analyze								
			data, and report results.								
	In	CO 5	Explain the principle of electrical transducers.								
			Confidence to apply instrumentation solutions for given								
			industrial applications.								

CO-PO Mapping:

Subject	Course Outcomes	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10	PO 11	PO 12
de J	CO 1	3	2	1	2	2							
4 ent & ion I	CO 2	2	3	1	2	3							
EI4-2 irem entat	CO 3	1	3	2	3	2							
4] Aeasu trum	CO 4	1	2	3	2	3							
	CO 5	1	2	3	3	3							
	•	3: Str	ongly	•	2:	Mode	rate	•	1: V	Veak			